Intel - EPF6024AQC240-3N Datasheet

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

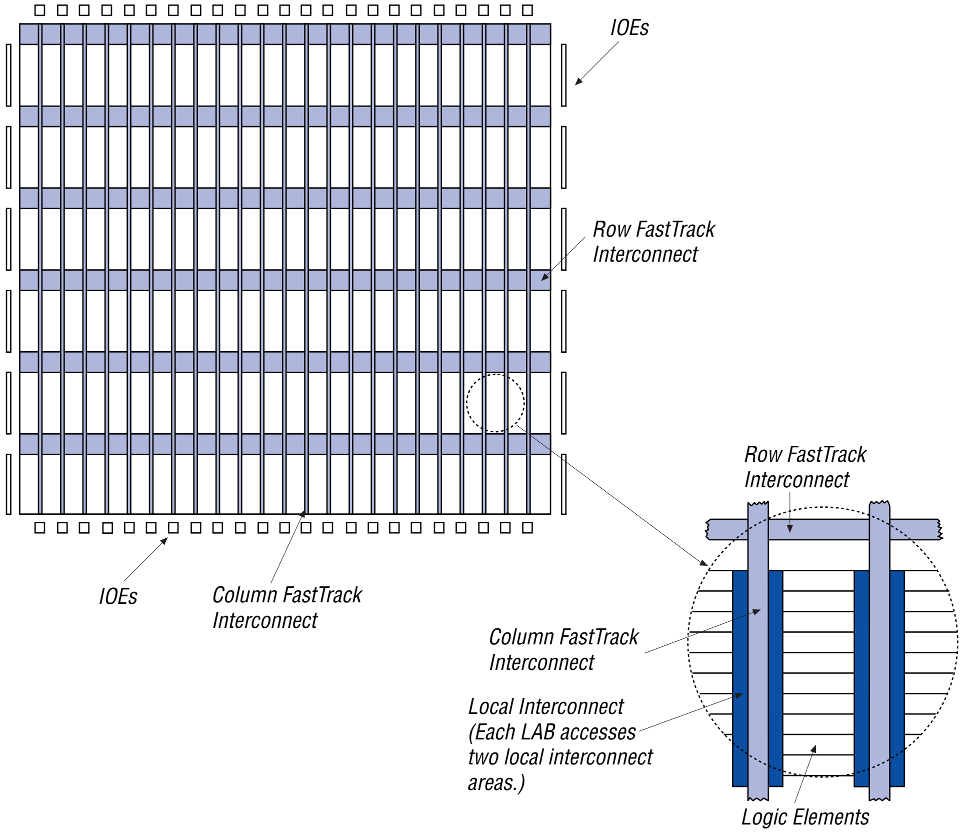
Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	196
Number of Logic Elements/Cells	1960
Total RAM Bits	-
Number of I/O	199
Number of Gates	24000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	240-BFQFP
Supplier Device Package	240-PQFP (32x32)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf6024aqc240-3n

Figure 1. OptiFLEX Architecture Block Diagram



FLEX 6000 devices provide four dedicated, global inputs that drive the control inputs of the flipflops to ensure efficient distribution of high-speed, low-skew control signals. These inputs use dedicated routing channels that provide shorter delays and lower skews than the FastTrack Interconnect. These inputs can also be driven by internal logic, providing an ideal solution for a clock divider or an internally generated asynchronous clear signal that clears many registers in the device. The dedicated global routing structure is built into the device, eliminating the need to create a clock tree.

Logic Array Block

An LAB consists of ten LEs, their associated carry and cascade chains, the LAB control signals, and the LAB local interconnect. The LAB provides the coarse-grained structure of the FLEX 6000 architecture, and facilitates efficient routing with optimum device utilization and high performance.

Figure 5. Carry Chain Operation

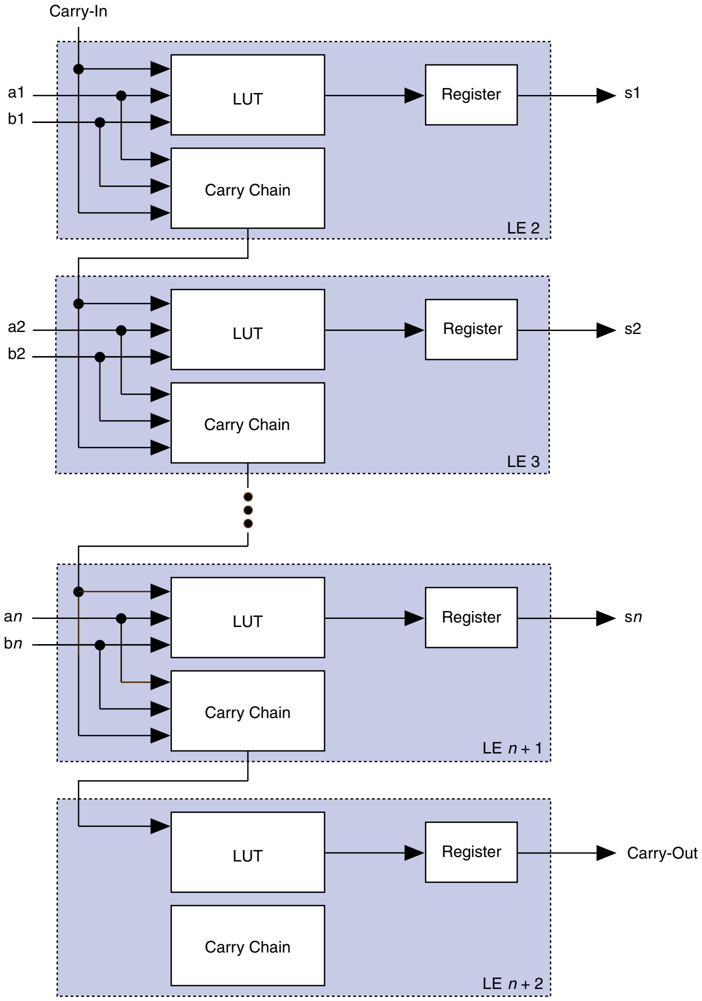
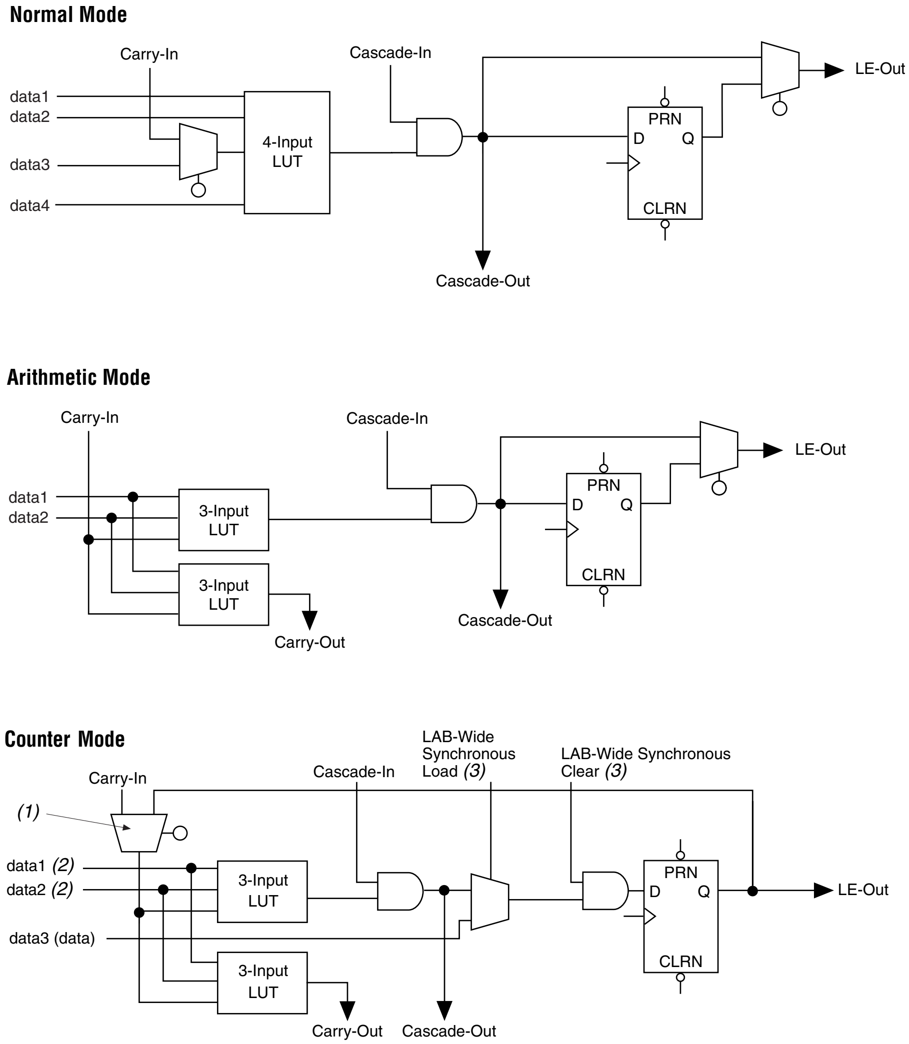


Figure 7. LE Operating Modes



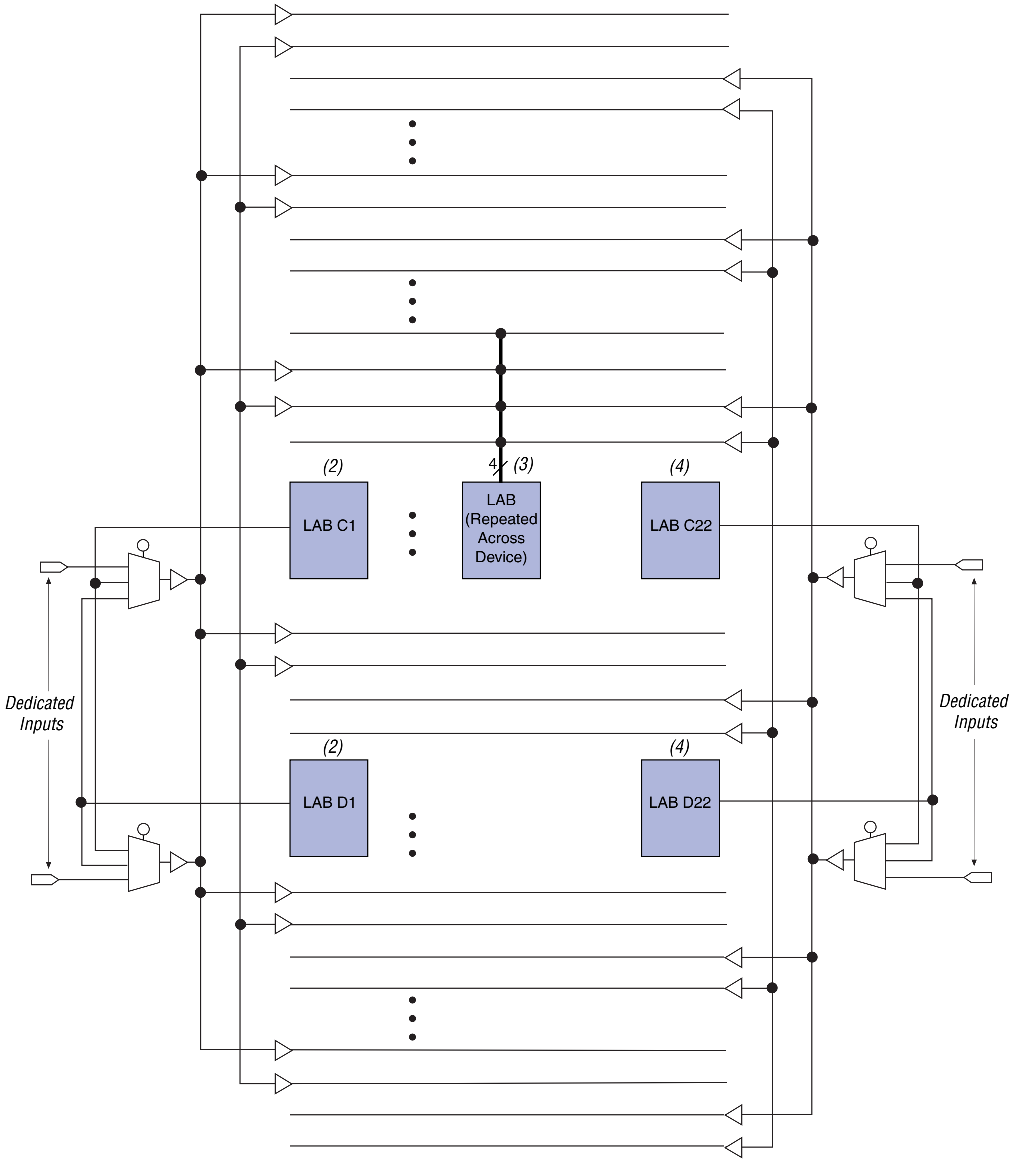
Notes:

(1) The register feedback multiplexer is available on LE 2 of each LAB.

(2) The `data1` and `data2` input signals can supply a clock enable, up or down control, or register feedback signals for all LEs other than the second LE in an LAB.

(3) The LAB-wide synchronous clear and LAB-wide synchronous load affect all registers in an LAB.

Figure 11. Global Clock & Clear Distribution Note (1)



Notes:

(1) The global clock and clear distribution signals are shown for EPF6016 and EPF6016A devices. In EPF6010A devices, LABs in rows B and C drive global signals. In EPF6024A devices, LABs in rows C and E drive global signals.
(2) The local interconnect from LABs C1 and D1 can drive two global control signals on the left side.
(3) Global signals drive into every LAB as clock, asynchronous clear, preset, and data signals.
(4) The local interconnect from LABs C22 and D22 can drive two global control signals on the right side.

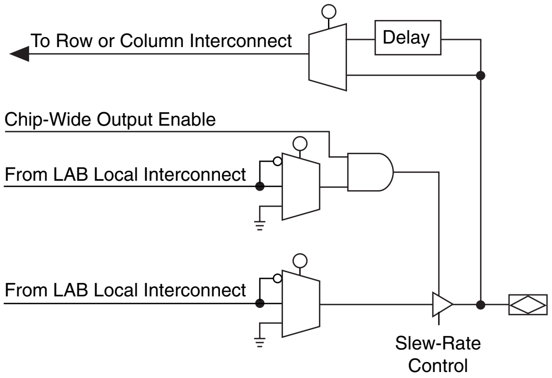
I/O Elements

An IOE contains a bidirectional I/O buffer and a tri-state buffer. IOEs can be used as input, output, or bidirectional pins. An IOE receives its data signals from the adjacent local interconnect, which can be driven by a row or column interconnect (allowing any LE in the device to drive the IOE) or by an adjacent LE (allowing fast clock-to-output delays). A FastFLEX™ I/O pin is a row or column output pin that receives its data signals from the adjacent local interconnect driven by an adjacent LE. The IOE receives its output enable signal through the same path, allowing individual output enables for every pin and permitting emulation of open-drain buffers. The Altera Compiler uses programmable inversion to invert the data or output enable signals automatically where appropriate. Open-drain emulation is provided by driving the data input low and toggling the OE of each IOE. This emulation is possible because there is one OE per pin.

A chip-wide output enable feature allows the designer to disable all pins of the device by asserting one pin (`DEV_OE`). This feature is useful during board debugging or testing.

Figure 12 shows the IOE block diagram.

Figure 12. IOE Block Diagram



Each IOE drives a row or column interconnect when used as an input or bidirectional pin. A row IOE can drive up to six row lines; a column IOE can drive up to two column lines. The input path from the I/O pad to the FastTrack Interconnect has a programmable delay element that can be used to guarantee a zero hold time. Depending on the placement of the IOE relative to what it is driving, the designer may choose to turn on the programmable delay to ensure a zero hold time. Figure 13 shows how an IOE connects to a row interconnect, and Figure 14 shows how an IOE connects to a column interconnect.

Figure 13. IOE Connection to Row Interconnect

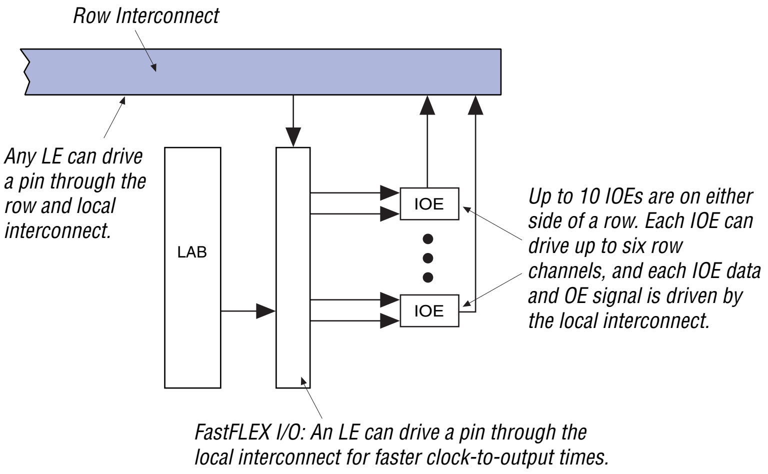
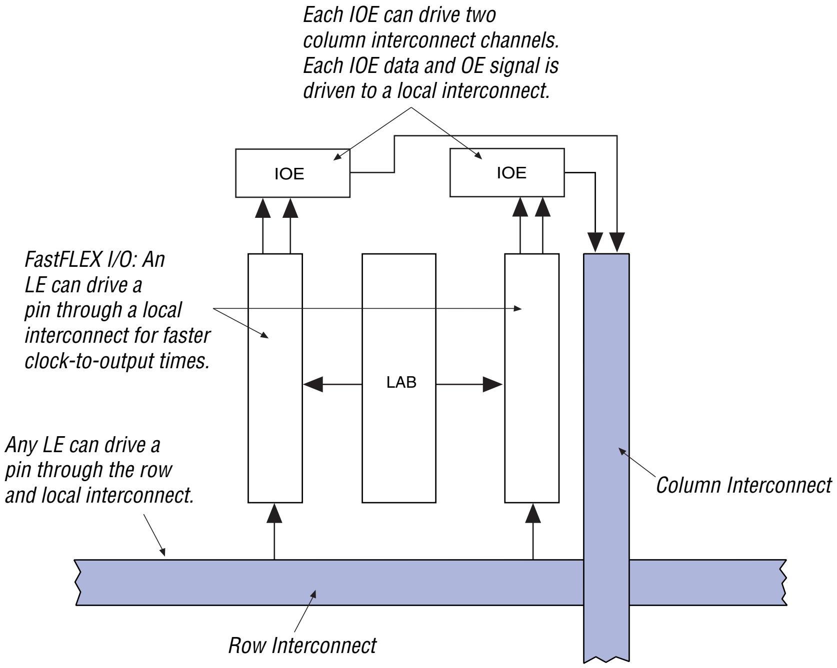


Figure 14. IOE Connection to Column Interconnect



SameFrame Pin-Outs

3.3-V FLEX 6000 devices support the SameFrame pin-out feature for FineLine BGA packages. The SameFrame pin-out feature is the arrangement of balls on FineLine BGA packages such that the lower-ball-count packages form a subset of the higher-ball-count packages. SameFrame pin-outs provide the flexibility to migrate not only from device to device within the same package, but also from one package to another. A given printed circuit board (PCB) layout can support multiple device density/package combinations. For example, a single board layout can support an EPF6016A device in a 100-pin FineLine BGA package or an EPF6024A device in a 256-pin FineLine BGA package.

The Altera software packages provide support to design PCBs with SameFrame pin-out devices. Devices can be defined for present and future use. The Altera software packages generate pin-outs describing how to lay out a board to take advantage of this migration (see Figure 15).

Figure 15. SameFrame Pin-Out Example

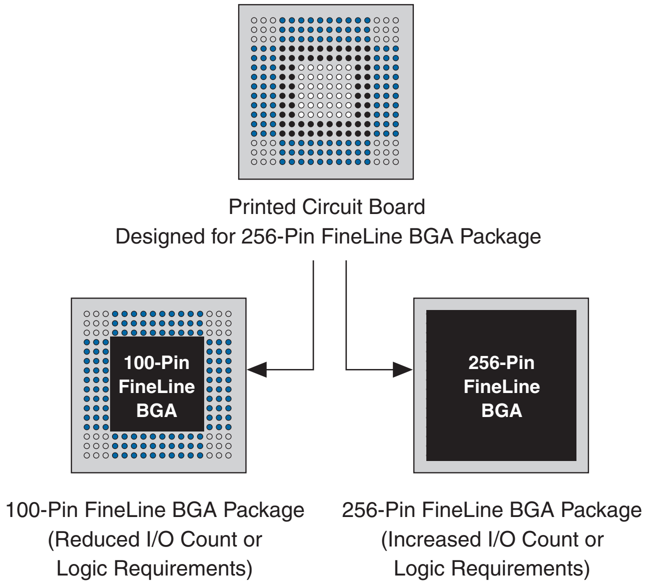


Table 6 lists the 3.3-V FLEX 6000 devices with the SameFrame pin-out feature.

Table 6. 3.3-V FLEX 6000 Devices with SameFrame Pin-Outs

Device	100-Pin FineLine BGA	256-Pin FineLine BGA
EPF6016A	v	v
EPF6024A		v

Output Configuration

This section discusses slew-rate control, the MultiVolt I/O interface, power sequencing, and hot-socketing for FLEX 6000 devices.

Slew-Rate Control

The output buffer in each IOE has an adjustable output slew-rate that can be configured for low-noise or high-speed performance. A slower slew-rate reduces system noise and adds a maximum delay of 6.8 ns. The fast slew-rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew-rate on a pin-by-pin basis during design entry or assign a default slew rate to all pins on a device-wide basis. The slew-rate setting affects only the falling edge of the output.

MultiVolt I/O Interface

The FLEX 6000 device architecture supports the MultiVolt I/O interface feature, which allows FLEX 6000 devices to interface with systems of differing supply voltages. The EPF6016 device can be set for 3.3-V or 5.0-V I/O pin operation. This device has one set of V_{CC} pins for internal operation and input buffers (`VCCINT`), and another set for output drivers (`VCCIO`).

The `VCCINT` pins on 5.0-V FLEX 6000 devices must always be connected to a 5.0-V power supply. With a 5.0-V V_{CCINT} level, input voltages are at TTL levels and are therefore compatible with 3.3-V and 5.0-V inputs.

The `VCCIO` pins on 5.0-V FLEX 6000 devices can be connected to either a 3.3-V or 5.0-V power supply, depending on the output requirements. When the `VCCIO` pins are connected to a 5.0-V power supply, the output levels are compatible with 5.0-V systems. When the `VCCIO` pins are connected to a 3.3-V power supply, the output high is 3.3 V and is therefore compatible with 3.3-V or 5.0-V systems. Devices operating with V_{CCIO} levels lower than 4.75 V incur a nominally greater timing delay of t_{OD2} instead of t_{OD1}.

On 3.3-V FLEX 6000 devices, the `VCCINT` pins must be connected to a 3.3-V power supply. Additionally, 3.3-V FLEX 6000A devices can interface with 2.5-V, 3.3-V, or 5.0-V systems when the `VCCIO` pins are tied to 2.5 V. The output can drive 2.5-V systems, and the inputs can be driven by 2.5-V, 3.3-V, or 5.0-V systems. When the `VCCIO` pins are tied to 3.3 V, the output can drive 3.3-V or 5.0-V systems. MultiVolt I/Os are not supported on 100-pin TQFP or 100-pin FineLine BGA packages.

Table 7 describes FLEX 6000 MultiVolt I/O support.

Table 7. FLEX 6000 MultiVolt I/O Support

V_{CCINT} (V)	V_{CCIO} (V)	Input Signal (V)			Output Signal (V)		
		2.5	3.3	5.0	2.5	3.3	5.0
3.3	2.5	v	v	v	v		
3.3	3.3	v	v	v	v *(1)*	v	v
5.0	3.3		v	v		v	v
5.0	5.0		v	v			v

Note:

(1) When V_{CCIO} = 3.3 V, a FLEX 6000 device can drive a 2.5-V device that has 3.3-V tolerant inputs.

Open-drain output pins on 5.0-V or 3.3-V FLEX 6000 devices (with a pull-up resistor to the 5.0-V supply) can drive 5.0-V CMOS input pins that require a V_{IH} of 3.5 V. When the open-drain pin is active, it will drive low. When the pin is inactive, the trace will be pulled up to 5.0 V by the resistor. The open-drain pin will only drive low or tri-state; it will never drive high. The rise time is dependent on the value of the pull-up resistor and load impedance. The I_{OL} current specification should be considered when selecting a pull-up resistor.

Output pins on 5.0-V FLEX 6000 devices with V_{CCIO} = 3.3 V or 5.0 V (with a pull-up resistor to the 5.0-V supply) can also drive 5.0-V CMOS input pins. In this case, the pull-up transistor will turn off when the pin voltage exceeds 3.3 V. Therefore, the pin does not have to be open-drain.

Power Sequencing & Hot-Socketing

Because FLEX 6000 family devices can be used in a mixed-voltage environment, they have been designed specifically to tolerate any possible power-up sequence. The V_{CCIO} and V_{CCINT} power planes can be powered in any order.

Signals can be driven into 3.3-V FLEX 6000 devices before and during power up without damaging the device. Additionally, FLEX 6000 devices do not drive out during power up. Once operating conditions are reached, FLEX 6000 devices operate as specified by the user.

IEEE Std. 1149.1 (JTAG) Boundary-Scan Support

All FLEX 6000 devices provide JTAG BST circuitry that comply with the IEEE Std. 1149.1-1990 specification. Table 8 shows JTAG instructions for FLEX 6000 devices. JTAG BST can be performed before or after configuration, but not during configuration (except when you disable JTAG support in user mode).

1 See *Application Note 39 (IEEE 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)* for more information on JTAG BST circuitry.

Table 8. FLEX 6000 JTAG Instructions

JTAG Instruction	Description
SAMPLE/PRELOAD	Allows a snapshot of the signals at the device pins to be captured and examined during normal device operation, and permits an initial data pattern to be output at the device pins.
EXTEST	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test result at the input pins.
BYPASS	Places the 1-bit bypass register between the `TDI` and `TDO` pins, which allows the BST data to pass synchronously through the selected device to adjacent devices during normal device operation.

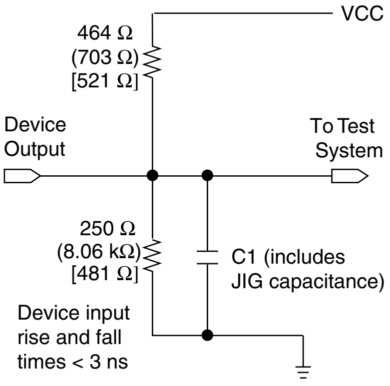
Table 10. JTAG Timing Parameters & Values

Symbol	Parameter	Min	Max	Unit
t_{JCP}	`TCK` clock period	100		ns
t_{JCH}	`TCK` clock high time	50		ns
t_{JCL}	`TCK` clock low time	50		ns
t_{JPSU}	JTAG port setup time	20		ns
t_{JPH}	JTAG port hold time	45		ns
t_{JPCO}	JTAG port clock-to-output		25	ns
t_{JPZX}	JTAG port high impedance to valid output		25	ns
t_{JPXZ}	JTAG port valid output to high impedance		25	ns
t_{JSSU}	Capture register setup time	20		ns
t_{JSH}	Capture register hold time	45		ns
t_{JSCO}	Update register clock-to-output		35	ns
t_{JSZX}	Update register high impedance to valid output		35	ns
t_{JSXZ}	Update register valid output to high impedance		35	ns

Generic Testing

Each FLEX 6000 device is functionally tested. Complete testing of each configurable SRAM bit and all logic functionality ensures 100% configuration yield. AC test measurements for FLEX 6000 devices are made under conditions equivalent to those shown in Figure 17. Multiple test patterns can be used to configure devices during all stages of the production flow.

Figure 17. AC Test Conditions



Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fast-ground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result. Numbers without parentheses are for 5.0-V devices or outputs. Numbers in parentheses are for 3.3-V devices or outputs. Numbers in brackets are for 2.5-V devices or outputs.

Operating Conditions

Tables 11 through 18 provide information on absolute maximum ratings, recommended operating conditions, operating conditions, and capacitance for 5.0-V and 3.3-V FLEX 6000 devices.

Table 11. FLEX 6000 5.0-V Device Absolute Maximum Ratings *Note (1)*

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to ground *(2)*	–2.0	7.0	V
V_I	DC input voltage		–2.0	7.0	V
I_{OUT}	DC output current, per pin		–25	25	mA
T_{STG}	Storage temperature	No bias	–65	150	° C
T_{AMB}	Ambient temperature	Under bias	–65	135	° C
T_J	Junction temperature	PQFP, TQFP, and BGA packages		135	° C

Table 12. FLEX 6000 5.0-V Device Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CCINT}	Supply voltage for internal logic and input buffers	*(3)*, *(4)*	4.75 (4.50)	5.25 (5.50)	V
V_{CCIO}	Supply voltage for output buffers, 5.0-V operation	*(3)*, *(4)*	4.75 (4.50)	5.25 (5.50)	V
	Supply voltage for output buffers, 3.3-V operation	*(3)*, *(4)*	3.00 (3.00)	3.60 (3.60)	V
V_I	Input voltage		–0.5	$V_{CCINT} + 0.5$	V
V_O	Output voltage		0	V_{CCIO}	V
T_J	Operating temperature	For commercial use	0	85	° C
		For industrial use	–40	100	° C
t_R	Input rise time			40	ns
t_F	Input fall time			40	ns

Timing Model

The continuous, high-performance FastTrack Interconnect routing resources ensure predictable performance and accurate simulation and timing analysis. This predictable performance contrasts with that of FPGAs, which use a segmented connection scheme and therefore have unpredictable performance.

Device performance can be estimated by following the signal path from a source, through the interconnect, to the destination. For example, the registered performance between two LEs on the same row can be calculated by adding the following parameters:

- LE register clock-to-output delay ($t_{CO} + t_{REG\_TO\_OUT}$)
- Routing delay ($t_{ROW} + t_{LOCAL}$)
- LE LUT delay ($t_{DATA\_TO\_REG}$)
- LE register setup time (t_{SU})

The routing delay depends on the placement of the source and destination LEs. A more complex registered path may involve multiple combinatorial LEs between the source and destination LEs.

Timing simulation and delay prediction are available with the Simulator and Timing Analyzer, or with industry-standard EDA tools. The Simulator offers both pre-synthesis functional simulation to evaluate logic design accuracy and post-synthesis timing simulation with 0.1-ns resolution. The Timing Analyzer provides point-to-point timing delay information, setup and hold time analysis, and device-wide performance analysis.

Figure 19 shows the overall timing model, which maps the possible routing paths to and from the various elements of the FLEX 6000 device.

Figure 19. FLEX 6000 Timing Model

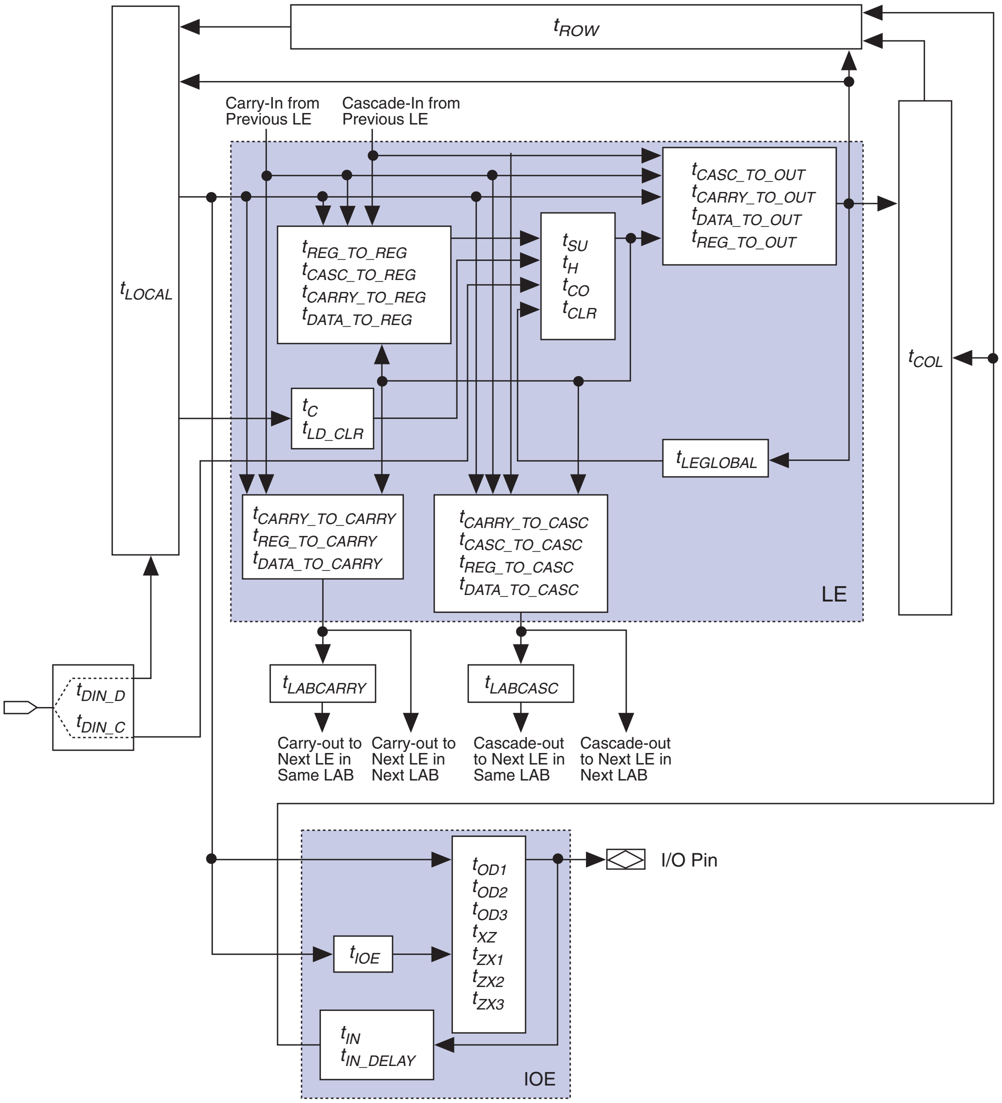


Table 23. External Timing Parameters

Symbol	Parameter	Conditions
t_{INSU}	Setup time with global clock at LE register	*(8)*
t_{INH}	Hold time with global clock at LE register	*(8)*
t_{OUTCO}	Clock-to-output delay with global clock with LE register using FastFLEX I/O pin	*(8)*

Notes to tables:

(1) Microparameters are timing delays contributed by individual architectural elements and cannot be measured explicitly.

(2) Operating conditions:
V_{CCIO} = 5.0 V ±5% for commercial use in 5.0-V FLEX 6000 devices.
V_{CCIO} = 5.0 V ±10% for industrial use in 5.0-V FLEX 6000 devices.
V_{CCIO} = 3.3 V ±10% for commercial or industrial use in 3.3-V FLEX 6000 devices.

(3) Operating conditions:
V_{CCIO} = 3.3 V ±10% for commercial or industrial use in 5.0-V FLEX 6000 devices.
V_{CCIO} = 2.5 V ±0.2 V for commercial or industrial use in 3.3-V FLEX 6000 devices.

(4) Operating conditions:
V_{CCIO} = 2.5 V, 3.3 V, or 5.0 V.

(5) These parameters are worst-case values for typical applications. Post-compilation timing simulation and timing analysis are required to determine actual worst-case performance.

(6) This timing parameter shows the delay of a register-to-register test pattern and is used to determine speed grades. There are 12 LEs, including source and destination registers. The row and column interconnects between the registers vary in length.

(7) This timing parameter is shown for reference and is specified by characterization.

(8) This timing parameter is specified by characterization.

Tables 24 through 28 show the timing information for EPF6010A and EPF6016A devices.

Table 24. LE Timing Microparameters for EPF6010A & EPF6016A Devices (Part 1 of 2)

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
$t_{REG\_TO\_REG}$		1.2		1.3		1.7	ns
$t_{CASC\_TO\_REG}$		0.9		1.0		1.2	ns
$t_{CARRY\_TO\_REG}$		0.9		1.0		1.2	ns
$t_{DATA\_TO\_REG}$		1.1		1.2		1.5	ns
$t_{CASC\_TO\_OUT}$		1.3		1.4		1.8	ns
$t_{CARRY\_TO\_OUT}$		1.6		1.8		2.3	ns
$t_{DATA\_TO\_OUT}$		1.7		2.0		2.5	ns
$t_{REG\_TO\_OUT}$		0.4		0.4		0.5	ns
t_{SU}	0.9		1.0		1.3		ns
t_H	1.4		1.7		2.1		ns

Table 26. Interconnect Timing Microparameters for EPF6010A & EPF6016A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{LOCAL}		0.7		0.7		1.0	ns
t_{ROW}		2.9		3.2		3.2	ns
t_{COL}		1.2		1.3		1.4	ns
t_{DIN_D}		5.4		5.7		6.4	ns
t_{DIN_C}		4.3		5.0		6.1	ns
$t_{LEGLOBAL}$		2.6		3.0		3.7	ns
$t_{LABCARRY}$		0.7		0.8		0.9	ns
$t_{LABCASC}$		1.3		1.4		1.8	ns

Table 27. External Reference Timing Parameters for EPF6010A & EPF6016A Devices

Parameter	Device	Speed Grade						Unit
		-1		-2		-3		
		Min	Max	Min	Max	Min	Max	
t_1	EPF6010A		37.6		43.6		53.7	ns
	EPF6016A		38.0		44.0		54.1	ns

Table 28. External Timing Parameters for EPF6010A & EPF6016A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.1 *(1)*		2.4 *(1)*		3.3 *(1)*		ns
t_{INH}	0.2 *(2)*		0.3 *(2)*		0.1 *(2)*		ns
t_{OUTCO}	2.0	7.1	2.0	8.2	2.0	10.1	ns

Notes:

(1) Setup times are longer when the *Increase Input Delay* option is turned on. The setup time values are shown with the *Increase Input Delay* option turned off.

(2) Hold time is zero when the *Increase Input Delay* option is turned on.

Tables 29 through 33 show the timing information for EPF6016 devices.

Table 29. LE Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
$t_{REG\_TO\_REG}$		2.2		2.8	ns
$t_{CASC\_TO\_REG}$		0.9		1.2	ns
$t_{CARRY\_TO\_REG}$		1.6		2.1	ns
$t_{DATA\_TO\_REG}$		2.4		3.0	ns
$t_{CASC\_TO\_OUT}$		1.3		1.7	ns
$t_{CARRY\_TO\_OUT}$		2.4		3.0	ns
$t_{DATA\_TO\_OUT}$		2.7		3.4	ns
$t_{REG\_TO\_OUT}$		0.3		0.5	ns
t_{SU}	1.1		1.6		ns
t_{H}	1.8		2.3		ns
t_{CO}		0.3		0.4	ns
t_{CLR}		0.5		0.6	ns
t_{C}		1.2		1.5	ns
t_{LD_CLR}		1.2		1.5	ns
$t_{CARRY\_TO\_CARRY}$		0.2		0.4	ns
$t_{REG\_TO\_CARRY}$		0.8		1.1	ns
$t_{DATA\_TO\_CARRY}$		1.7		2.2	ns
$t_{CARRY\_TO\_CASC}$		1.7		2.2	ns
$t_{CASC\_TO\_CASC}$		0.9		1.2	ns
$t_{REG\_TO\_CASC}$		1.6		2.0	ns
$t_{DATA\_TO\_CASC}$		1.7		2.1	ns
t_{CH}	4.0		4.0		ns
t_{CL}	4.0		4.0		ns

Table 30. IOE Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{OD1}		2.3		2.8	ns
t_{OD2}		4.6		5.1	ns

Table 30. IOE Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{OD3}		4.7		5.2	ns
t_{XZ}		2.3		2.8	ns
t_{ZX1}		2.3		2.8	ns
t_{ZX2}		4.6		5.1	ns
t_{ZX3}		4.7		5.2	ns
t_{IOE}		0.5		0.6	ns
t_{IN}		3.3		4.0	ns
t_{IN_DELAY}		4.6		5.6	ns

Table 31. Interconnect Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{LOCAL}		0.8		1.0	ns
t_{ROW}		2.9		3.3	ns
t_{COL}		2.3		2.5	ns
t_{DIN_D}		4.9		6.0	ns
t_{DIN_C}		4.8		6.0	ns
$t_{LEGLOBAL}$		3.1		3.9	ns
$t_{LABCARRY}$		0.4		0.5	ns
$t_{LABCASC}$		0.8		1.0	ns

Table 32. External Reference Timing Parameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
$\mathbf{t_1}$		53.0		65.0	ns
$\mathbf{t_{DRR}}$		16.0		20.0	ns

Table 38. External Timing Parameters for EPF6024A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.0 (1)		2.2 (1)		2.6 (1)		ns
t_{INH}	0.2 (2)		0.2 (2)		0.3 (2)		ns
t_{OUTCO}	2.0	7.4	2.0	8.2	2.0	9.9	ns

Notes:

(1) Setup times are longer when the *Increase Input Delay* option is turned on. The setup time values are shown with the *Increase Input Delay* option turned off.

(2) Hold time is zero when the *Increase Input Delay* option is turned on.

Power Consumption

The supply power (P) for FLEX 6000 devices can be calculated with the following equations:

$$P = P_{INT} + P_{IO}$$
$$P = (I_{CCSTANDBY} + I_{CCACTIVE}) \times V_{CC} + P_{IO}$$

Typical $I_{CCSTANDBY}$ values are shown as I_{CC0} in the "FLEX 6000 Device DC Operating Conditions" table on pages 31 and 33 of this data sheet. The $I_{CCACTIVE}$ value depends on the switching frequency and the application logic. This value is based on the amount of current that each LE typically consumes. The P_{IO} value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

The $I_{CCACTIVE}$ value can be calculated with the following equation:

$$I_{CCACTIVE} = K \times \mathbf{f_{MAX}} \times N \times \mathbf{tog_{LC}} \times \frac{\mu A}{MHz \times LE}$$

Where:

$\mathbf{f_{MAX}}$ = Maximum operating frequency in MHz
N = Total number of LEs used in a FLEX 6000 device
$\mathbf{tog_{LC}}$ = Average percentage of LEs toggling at each clock (typically 12.5%)
K = Constant, shown in Table 39

Table 39. K Constant Values

Device	K Value
EPF6010A	14
EPF6016	88
EPF6016A	14
EPF6024A	14

This calculation provides an I_{CC} estimate based on typical conditions with no output load. The actual I_{CC} should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.

To better reflect actual designs, the power model (and the constant K in the power calculation equations shown above) for continuous interconnect FLEX devices assumes that LEs drive FastTrack Interconnect channels. In contrast, the power model of segmented FPGAs assumes that all LEs drive only one short interconnect segment. This assumption may lead to inaccurate results, compared to measured power consumption for an actual design in a segmented interconnect FPGA.

Figure 20 shows the relationship between the current and operating frequency for EPF6010A, EPF6016, EPF6016A, and EPF6024A devices.